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<b>INFORMATION DISCLOSURE STATEMENT BY APPLICANT</b> <i>(use as many sheets as necessary)</i>				Application Number	Unknown <b>107562006</b>
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				First Named Inventor	Gyu-Chul YI
				Art Unit	Unknown
				Examiner Name	Unknown
Sheet	1	of	1	Attorney Docket Number	Q92105

<b>U.S. PATENT DOCUMENTS</b>					
Examiner Initials*	Cite No. <sup>1</sup>	Document Number		Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document
		Number	Kind Code <sup>2</sup> (if known)		
	US				

<b>FOREIGN PATENT DOCUMENTS</b>						
Examiner Initials*	Cite No. <sup>1</sup>	Foreign Patent Document		Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Translation <sup>6</sup>
		Country Code <sup>3</sup>	Number <sup>4</sup>			
	EP	1 258 928	A1	11-20-2002	Japanese Science and Technology Corp.	
	KR	2001-70678	A	07-27-2001	Kim et al.	

<b>NON PATENT LITERATURE DOCUMENTS</b>					
Examiner Initials*	Cite No. <sup>1</sup>	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city, and/or country where published.			Translation <sup>6</sup>
		S. Muthukumar et al., "Selective MOCVD Growth of ZnO Nanotips", <i>IEEE Transactions on nanotechnology</i> , Vol. 2, No. 1, March 2003, pp. 50-54			
		J. Zhong et al., "ZnO nanotips grown on Si substrates by Metal-Organic Chemical-Vapor Deposition", <i>Journal of Electronic Materials</i> , Vol. 33, No. 6, June 1, 2004, pp. 654-657			

Examiner Signature		Date Considered	
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\*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

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